



Description

The XPX40N008LL uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. It can be used in a wide variety of applications.

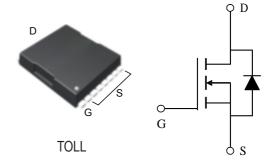
General Features

- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E_{AS}
- Excellent package for good heat dissipation

Application

- PWM
- Load Switching

VDS = 40V, ID = 400A RDS(ON) = 0.6mΩ (typ) @ VGS = 10V RDS(ON) = 0.9mΩ (typ) @ VGS = 4.5V



Package Marking and Ordering Information

Device	Pack	Marking	Qty(PCS)
XPX40N008LL	TOLL	40N008 XXXX YYYY	

Absolute Maximum Ratings (T_C=25°Cunless otherwise noted)

Symbol	Parameter	Rating	Units
VDS	Drain-Source Voltage	40	V
VGS	Gate-Source Voltage	±20	V
I _D @T _C =25°C	Continuous Drain Current, V _{GS} @ 10V ¹	400	А
I _D @T _C =100°C	Continuous Drain Current, V _{GS} @ 10V ¹	250	А
IDM	Pulsed Drain Current ²	750	А
EAS	Single Pulse Avalanche Energy ³	1406	mJ
IAS	Avalanche Current	85	А
P _D @T _C =25°C	Total Power Dissipation ⁴	500	W
TSTG	Storage Temperature Range	-55 to 150	℃
TJ	Operating Junction Temperature Range	-55 to 150	℃
R _θ JA	Thermal Resistance Junction-Ambient ¹	62	°C/W
R₀JC	Thermal Resistance Junction-Case ¹	0.8	°C/W



Electrical Characteristics (T_A = 25°C unless otherwise noted)

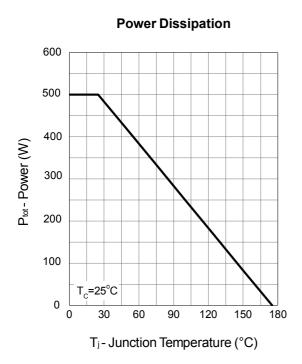
Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit	
Static Cha	Static Characteristics						
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V, I _{DS} =250μA	40	-	-	V	
	Zana Cata Valtaria Dunin Cumunt	V _{DS} =32V, V _{GS} =0V	-	-	1		
I _{DSS}	Zero Gate Voltage Drain Current	T _J =85°C	ı	-	30	μА	
$V_{GS(th)}$	Gate Threshold Voltage	V_{DS} = V_{GS} , I_{DS} =250 μ A	1.5	2	2.5	V	
I_{GSS}	Gate Leakage Current	V_{GS} =±20V, V_{DS} =0V		-	±100	nA	
•		V _{GS} =10V, I _{DS} =5 <u>0</u> A	-	0.6	0.8		
R _{DS(ON)}	Drain-Source On-state Resistance	T _J =125°C	ı	1.4	-	mΩ	
		V _{GS} =4.5V, I _{DS} =50A	-	0.9	1.3		
Gfs	Forward Transconductance	V _{DS} =5V, I _{DS} =50A	-	3.5	-	S	
Diode Characteristics							
V_{SD}^{e}	Diode Forward Voltage	I _{SD} =20A, V _{GS} =0V	-	0.78	1.1	V	
t _m	Reverse Recovery Time		-	61	-		
t _a	Charge Time	_I _{SD} =50A, dI _{SD} /dt=100A/μs	ı	31	-	ns	
t _b	Discharge Time	V _{dd} =20V	-	30	-		
Q _{rr}	Reverse Recovery Charge		ı	67	-	nC	
Dynamic	Characteristics ^f						
R_G	Gate Resistance	V_{GS} =0V, V_{DS} =0V, F =1MHz	0.6	0.9	2	Ω	
C _{iss}	Input Capacitance	_V _{GS} =0V,	-	7338	-		
C _{oss}	Output Capacitance	V _{DS} =20V,	-	2000	-	pF	
C _{rss}	Reverse Transfer Capacitance	Frequency=1.0MHz	-	175	-		
t _{d(ON)}	Turn-on Delay Time		-	18.8	-		
t _r	Turn-on Rise Time	V_{DD} =20V, R_L =20 Ω , I_{DS} =1A, V_{GEN} =10V,	ı	9.8	-	200	
t _{d(OFF)}	Turn-off Delay Time	$R_G=1\Omega$	-	50	-	ns	
t _f	Turn-off Fall Time		_	90.8	-		
Gate Cha	rge Characteristics ^f						
Qg	Total Gate Charge		-	92.8	-		
Q _{gth}	Threshold Gate Charge	V _{DS} =20V,	-	15.84	-		
Q_{gs}	Gate-Source Charge	V _{GS} =10V, I _{DS} =50A	-	24.75	-	nC	
Q _{gd}	Gate-Drain Charge		-	15.63	-		

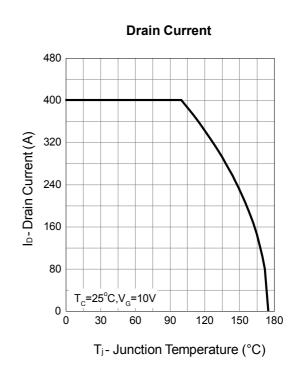
Note e[:] Pulse test; pulse width≤300µs, duty cycle≤2%.

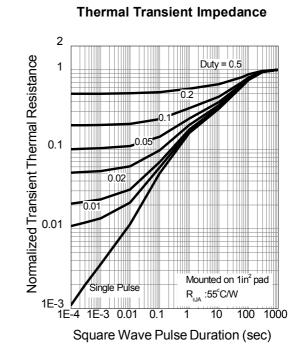
Note f Guaranteed by design, not subject to production testing.



Typical Operating Characteristics

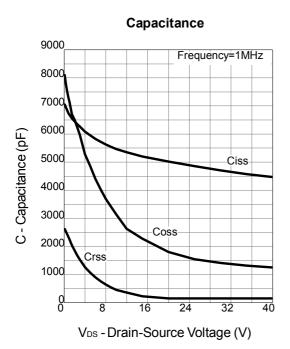


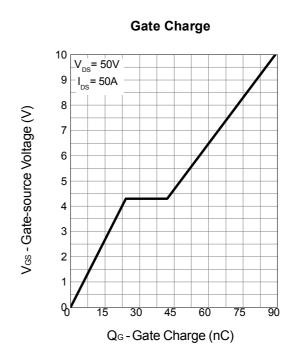


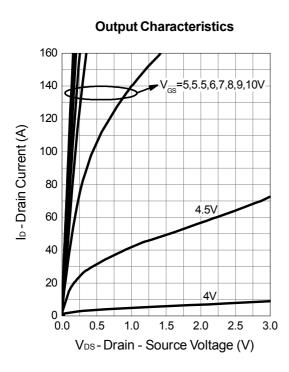


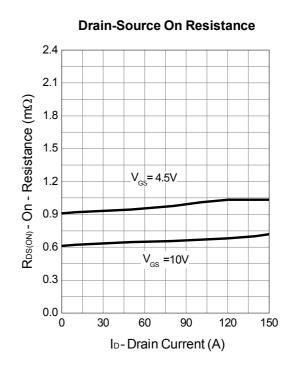


Typical Operating Characteristics (Cont.)



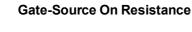


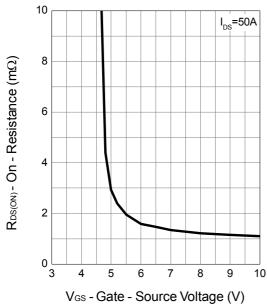




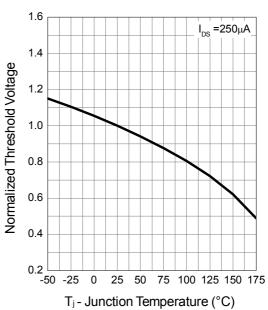


Typical Operating Characteristics (Cont.)

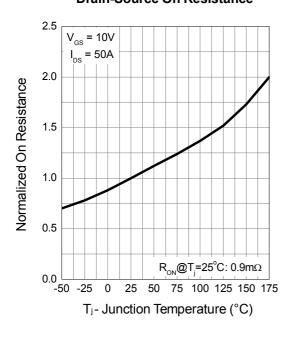




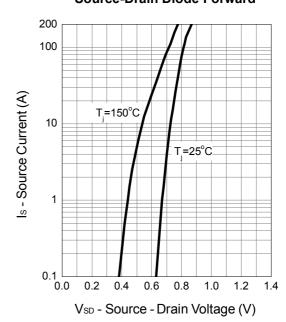
Gate Threshold Voltage



Drain-Source On Resistance

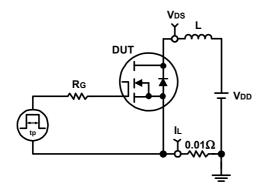


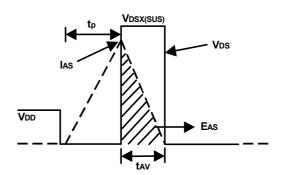
Source-Drain Diode Forward



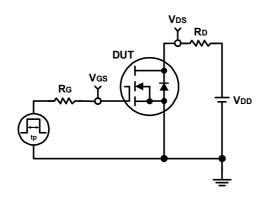


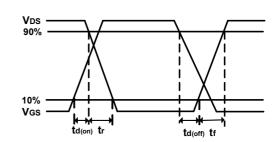
Avalanche Test Circuit and Waveforms





Switching Time Test Circuit and Waveforms

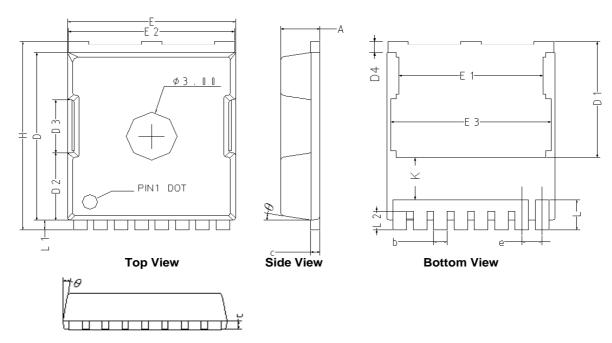






Package Information

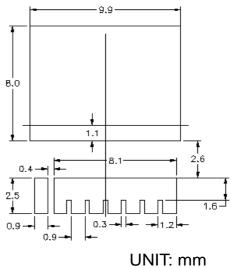
TOLL



Side	View
------	------

		, vicw		
	TO-LL			
SYMBOLS	MILLIN	MILLIMETERS INCHES		HES
	MIN.	MAX.	MIN.	MAX.
Α	2.20	2.40	0.087	0.094
b	0.70	0.90	0.028	0.035
С	0.40	0.60	0.016	0.024
D	10.23	10.63	0.403	0.419
D1	7.05	7.45	0.278	0.293
D2	3.98	4.38	0.157	0.172
D3	3.10	3.50	0.122	0.138
D4	0.50	0.90	0.020	0.035
E	9.70	10.10	0.382	0.398
E1	8.30	8.70	0.327	0.343
E2	9.60	10.00	0.378	0.394
E3	9.26	9.66	0.365	0.380
H	11.53	11.93	0.454	0.470
е	1.2	BSC	0.0472 BSC	
K	2.43	2.83	0.096	0.111
L	1.65	2.05	0.065	0.081
L1	0.40	0.80	0.016	0.031
L2	0.95	1.35	0.037	0.053
θ	6°	10°	6°	10°

RECOMMENDED LAND PATTERN





Flow (wave) soldering (solder dipping)

Product	Peak Temperature	Dipping Time
Pb device	245℃±5℃	5sec±1sec
Pb-Free device	260℃+0/-5℃	5sec±1sec



This integrated circuit can be damaged by ESD UniverChip Corporation recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedure can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

Attention:

- Any and all XPX power products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your XPX power representative nearest you before using any XPX power products described or contained herein in such applications.
- XPX power assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all XPX power products described or contained herein.
- Specifications of any and all XPX power products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.
- XPX power Semiconductor CO.,LTD. strives to supply high-quality high-reliability products. However, any and all semiconductor products fail with some probability. It is possible that these probabilistic failures could give rise to accidents or events that could endanger human lives, that could give rise to smoke or fire, or that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- In the event that any or all XPX power products(including technical data, services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported without obtaining the export license from the authorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written permission of XPX power Semiconductor CO.,LTD.
- Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production. XPX power believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.
- Any and all information described or contained herein are subject to change without notice due to product/ technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the XPX power product that you intend to use.
- This catalog provides information as of Sep.2019. Specifications and information herein are subject to change without notice.